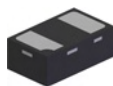


Features

- Ultra Low Forward Voltage Drop
- Superior Reverse Avalanche Capability
- Patented Super Barrier Rectifier Technology
- Soft, Fast Switching Capability
- 150°C Operating Junction Temperature
- **Lead Free by Design, RoHS Compliant (Note 1)**
- **"Green" Device (Note 2)**

Mechanical Data

- Case: DFN1006H4-2
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminal Connections: Cathode Dot
- Terminals: Finish - NiPdAu over Copper leadframe. Solderable per MIL-STD-202, Method 208
- Marking Information: See Page 2
- Ordering Information: See Page 2
- Weight: 0.001 grams (approximate)



Bottom View

Maximum Ratings @T_A = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load.
For capacitance load, derate current by 20%.

Characteristic	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _{RM}	20	V
RMS Reverse Voltage	V _{R(RMS)}	14	V
Average Rectified Output Current (See Figure 1)	I _O	700	mA
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load	I _{FSM}	7	A

Thermal Characteristics @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Maximum Thermal Resistance (Note 3)	R _{θJA}	224	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-65 to +150	°C

Electrical Characteristics @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse Breakdown Voltage (Note 4)	V _{(BR)R}	20	-	-	V	I _R = 50μA
Forward Voltage Drop	V _F	-	0.34 0.46 0.51 0.48	0.38 0.50 0.55 0.51	V	I _F = 0.1A, T _J = 25°C I _F = 0.5A, T _J = 25°C I _F = 0.7A, T _J = 25°C I _F = 0.7A, T _J = 125°C
Leakage Current (Note 4)	I _R	-	6 1.5	50 5	μA mA	V _R = 20V, T _J = 25°C V _R = 20V, T _J = 150°C

- Notes:
1. No purposefully added lead.
 2. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.
 3. Device mounted on FR-4 substrate. 2" x 2" 2oz. Copper, single sided PCB board.
 4. Short duration pulse test used to minimize self-heating effect.

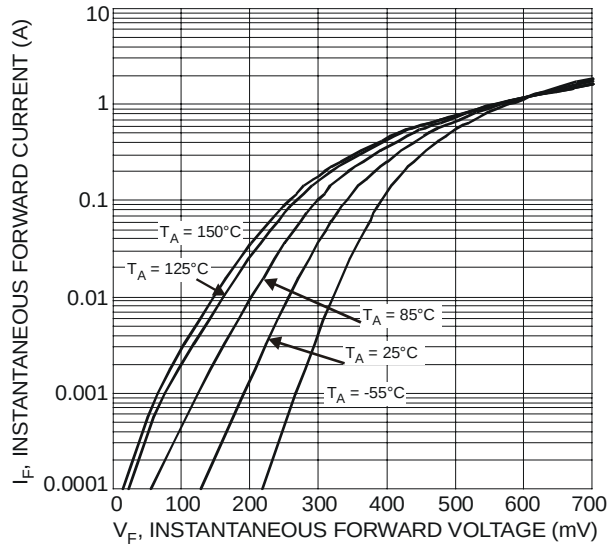


Fig. 1 Typical Forward Characteristics

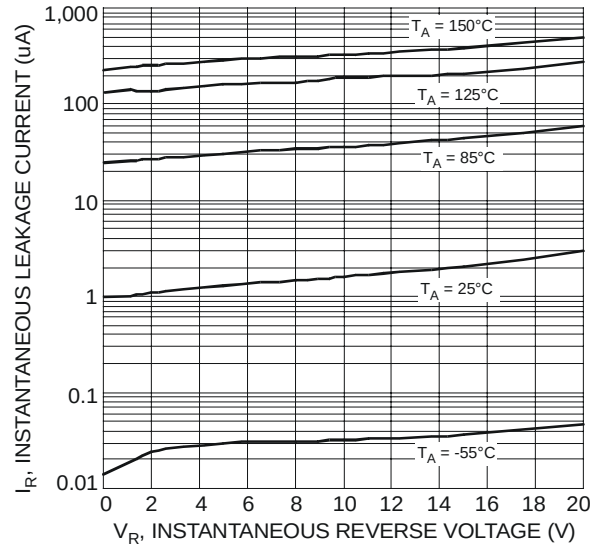


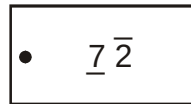
Fig. 2 Typical Reverse Characteristics

Ordering Information (Note 5)

Part Number	Case	Packaging
SBR07U20LPS-7	DFN1006H4-2	3000/Tape & Reel

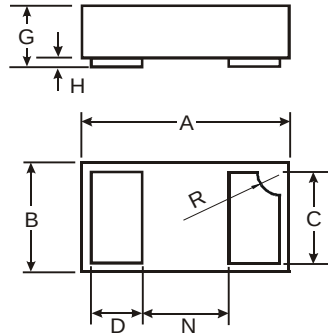
Notes: 5. For packaging details, go to our website at <http://www.diodes.com/datasheets/ap02007.pdf>.

Marking Information



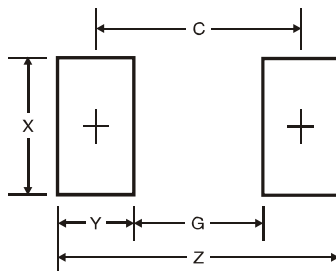
$\overline{72}$ = Product Type Marking Code
Dot Denotes Cathode Side

Package Outline Dimensions



DFN1006H4-2			
Dim	Min	Max	Typ
A	0.95	1.075	1.00
B	0.55	0.675	0.60
C	0.45	0.55	0.50
D	0.20	0.30	0.25
G	0.34	0.4	0.37
H	0	0.05	0.03
N	—	—	0.40
R	0.05	0.15	0.10
All Dimensions in mm			

Suggested Pad Layout



Dimensions	Value (in mm)
Z	1.1
G	0.3
X	0.7
Y	0.4
C	0.7

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SBR07U20LPS

Document number: DS31358 Rev. 2 - 2

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